



### Features

- Adopt FRD chip
- Low forward Voltage drop
- Fast reverse recovery time
- High frequency operation
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- Guard ring for enhanced ruggedness and long term reliability

### Typical Applications

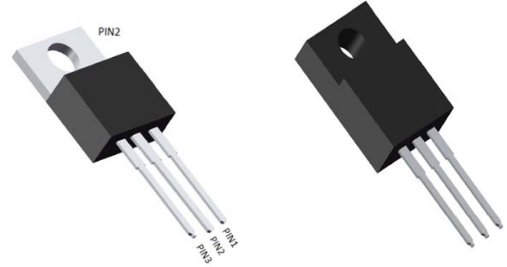
Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

### Mechanical Data

- **Package:** TO-220AB  
Molding compound meets UL 94 V-0 flammability rating, RoHS-compliant
- **Terminals:** Tin plated leads, solderable per J-STD-002 and JESD22-B102
- **Polarity:** As marked

TO-220AB

ITO-220AB/TO-220F



MUR1060CT(TO-220AB)  
MUR1060FCT(TO-220F)

MUR1060CTR(TO-220AB)  
MUR1060FCTR(TO-220F)

### ■Maximum Ratings (Ta=25°C Unless otherwise specified)

TYPE	V <sub>RSM</sub> V	V <sub>RRM</sub> V
MUR1060CT/CTR MUR1060FCT/FCTR	600	600

PARAMETER	SYMBOL	UNIT	MUR1060CT/MUR1060CTR/MUR1060FCT/MUR1060FCTR
Device marking code			MUR1060CT/MUR1060CTR/MUR1060FCT/MUR1060FCTR
Repetitive Peak Reverse Voltage	V <sub>RRM</sub>	V	600
Average Rectified Output Current @60Hz sine wave, R-load, T <sub>c</sub> (FIG.1)	I <sub>o</sub>	A	10
Surge(Non-repetitive)Forward Current @60Hz half sine-wave, 1 cycle, T <sub>j</sub> =25°C	I <sub>FSM</sub>	A	120
Current Squared Time @1ms≤t≤8.3ms T <sub>j</sub> =25°C,	I <sup>2</sup> t	A <sup>2</sup> s	10
Storage Temperature	T <sub>stg</sub>	°C	-55 ~ +175
Junction Temperature	T <sub>j</sub>	°C	-55 ~ +175
Typical Junction capacitance @4V,1MHz	C <sub>j</sub>	pF	20



## ■Electrical Characteristics

PARAMETER	SYMBOL	UNIT	TEST CONDITIONS	Min	Typ	Max
Instantaneous forward voltage drop per diode	$V_{FM}$	V	$I_{FM}=5.0A @T_j=25^{\circ}C$	-	1.55	1.75
			$I_{FM}=5.0A @T_j=150^{\circ}C$		1.45	1.6
DC reverse current at rated DC blocking voltage per diode	$I_{RRM1}$	uA	$V_{RM}=V_{RRM}$ $T_j=25^{\circ}C$	-	-	5.0
	$I_{RRM2}$		$V_{RM}=V_{RRM}$ $T_j=150^{\circ}C$	-	35	200
Reverse Recovery Time	$T_{rr}$	ns	$I_F=0.5A I_{RM}=1A$ $I_{RR}=0.25A T_j=25^{\circ}C$	-	35	50
			$T_j=25^{\circ}C$	-	50.8	-
			$T_j=125^{\circ}C$	-	81.8	-
Peak recovery current	$I_{RRM}$	A	$T_j=25^{\circ}C$	-	3.06	-
			$T_j=125^{\circ}C$			
Reverse recovery charge	$Q_{rr}$	nC	$T_j=25^{\circ}C$	-	78.88	-
			$T_j=125^{\circ}C$	-	280	-

## ■Thermal Characteristics ( $T_j=25^{\circ}C$ Unless otherwise specified)

PARAMETER		SYMBOL	UNIT	MUR1060CT/CTR
Thermal Resistance	Between junction and case	$R_{\theta J-C}$	$^{\circ}C/W$	2.0
Thermal Resistance	Between junction and Air	$R_{\theta J-A}$	$^{\circ}C/W$	50

## ■Ordering Information (Example)

PREFERRED P/N	UNIT WEIGHT(g)	MINIMUM PACKAGE(pcs)	INNER BOX QUANTITY(pcs)	OUTER CARTON QUANTITY(pcs)	DELIVERY MODE
MUR1060CT/CTR MUR1060FCT/FCTR	Approximate 1.88	50	1000	5000	Tube

## ■Characteristics (Typical)

FIG1:  $I_o$  - $T_c$  Curve

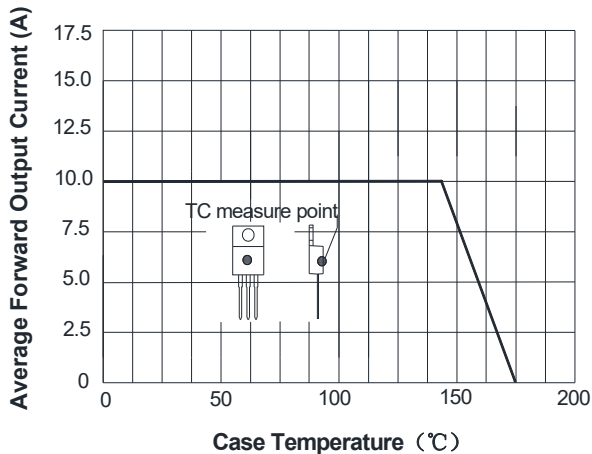
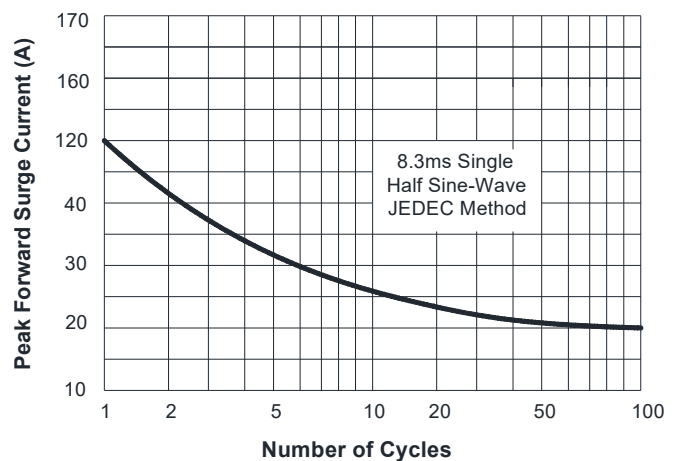
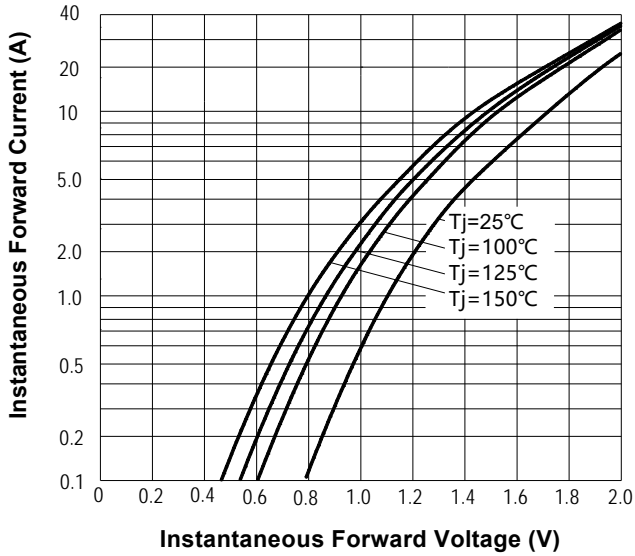


FIG2: Surge Forward Current Capability

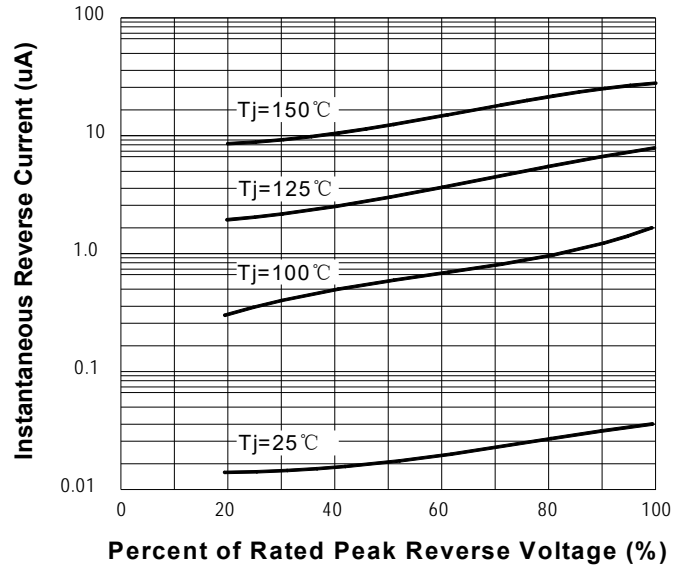




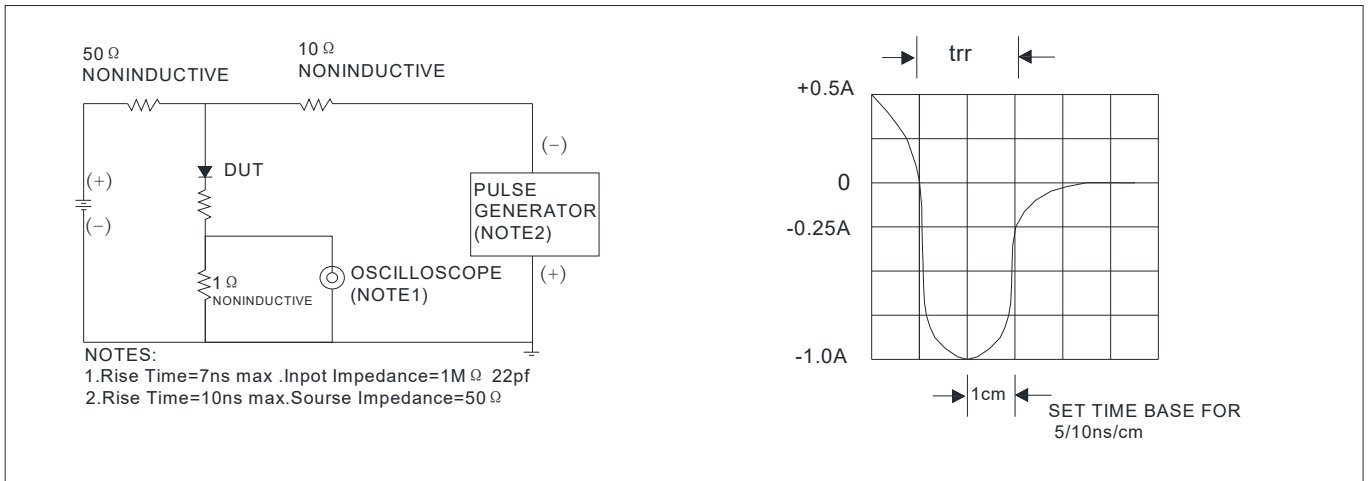
**FIG3: Forward Voltage**



**FIG.4: Instantaneous Reverse Characteristics**

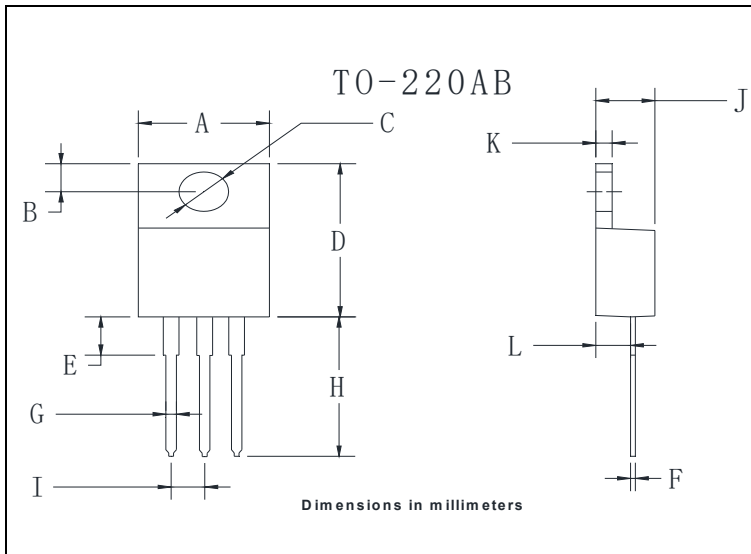


**FIG.5: Diagram of circuit and Testing wave form of reverse recovery time**

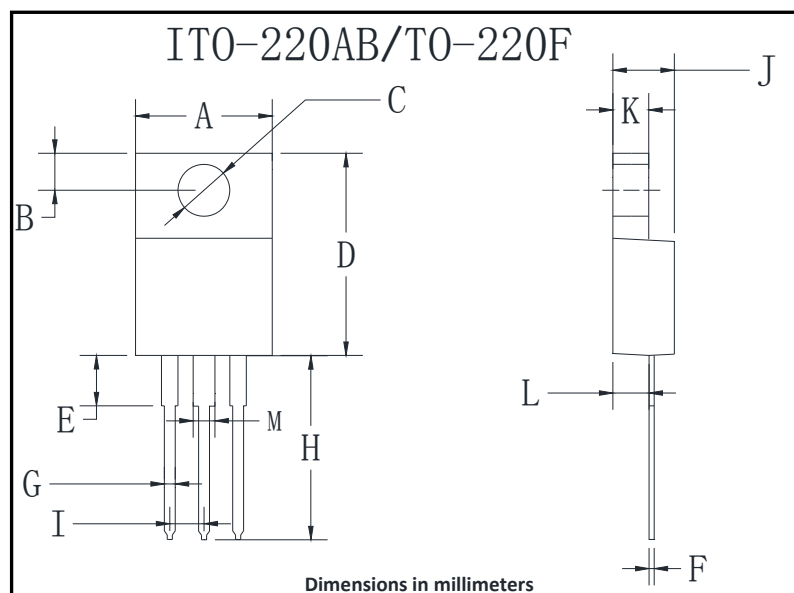




## ■ Outline Dimensions



TO-220AB		
Dim	Min	Max
A	9.95	10.35
B	2.55	2.95
C	3.8	4.0
D	14.95	15.25
E	3.75	4.25
F	0.26	0.5
G	0.68	0.94
H	13.4	13.9
I	2.35	2.65
J	4.38	4.78
K	1.14	1.4
L	2.37	2.79



ITO-220AB/TO-220F		
Dim	Min	Max
A	9.8	10.2
B	2.25	2.75
C	2.95	3.45
D	14.75	15.25
E	3.05	3.95
F	0.45	0.75
G	0.45	0.75
H	13.4	14.2
I	2.35	2.75
J	4.3	4.8
K	2.58	2.82
L	2.58	2.82
M	1.47	1.77

Package	Packing	Box Size L×W×H(mm)	Quantity(pcs/box)	Carton Size L×W×H(mm)	Quantity(pcs/carton)
TO-220AB	50pcs/Tube	558×148×38	1000	565×225×175	5000